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# Synthesis and characterization of structural, morphological and photosensor properties of Cu<sub>0.1</sub>Zn<sub>0.9</sub>S thin film prepared by a facile chemical method \;

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The Cu<sub>0.1</sub>Zn<sub>0.9</sub>S thin film was grown by facile chemical bath deposition (CBD) method on glass substrates at 60°C. The structural, morphological, photosensor properties of the as-grown thin film has been investigated. The structural and phase confirmation of the as-grown thin film was carried out by X-ray diffraction (XRD) technique and Raman spectroscopy. The FE-SEM images showed that the thin films are well covered with material on an entire glass substrate. From the optical absorption spectrum, the direct band gap energy for the Cu<sub>0.1</sub>Zn<sub>0.9</sub>S thin film was found to be ~3.16 eV at room temperature. The electrical properties were measured at room temperature in the voltage range  $\pm 2.5$  V, showed a drastic enhancement in current under light illumination with the highest photosensitivity of ~72 % for 260 W.

#### Topics

Electrical properties and parameters, Photodetectors, Glass, Absorption spectroscopy, Raman spectroscopy, Thin films, X-ray diffraction

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